

MiniSKiiP® 2

Twin 6-pack

SKiiP 23ACC12T4V10

Features

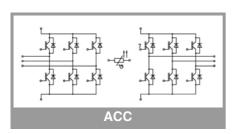
- Trench 4 IGBTs
- Robust and soft freewheeling diodes in CAL technology
- Highly reliable spring contacts for electrical connections
- UL recognised: File no. E63532

Typical Applications*

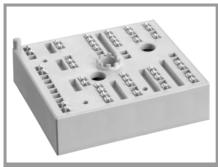
• 4Q inverters

Remarks

- Max. case temperature limited to T_C=125°C
- Product reliability results valid for T_j≤150°C (recommended T_{j,op}=-40...+150°C)
- Terminal distances sufficient for basic insulation in 3-phase 480VAC TN systems
- DC-link voltage V_{DC}≤800V
- Temperature sensor: no basic insulation to main circuit, signal processing with reference to –DC potential
- Please refer to MiniSKiiP "Technical Explanations" and "Mounting Instructions" for further information



| Absolute | Maximum Rating | S | | | |
|--------------------------------------|--|--|--------------------|------|--|
| Symbol | Conditions | | Values | Unit | |
| IGBT 1 - 6 | | | 3 4 | 0 | |
| V _{CES} | T _i = 25 °C | | 1200 | V | |
| I _C | , | T _s = 25 °C | 28 | A | |
| 10 | $\lambda_{\text{paste}} = 0.8 \text{ W/(mK)}$ $T_{\text{i}} = 175 \text{ °C}$ | $T_s = 70 ^{\circ}\text{C}$ | 23 | A | |
| I _C | | $T_s = 70^{\circ} \text{C}$ | 31 | A | |
| ıC | λ_{paste} =2.5 W/(mK) T _i = 175 °C | $T_s = 70 ^{\circ}\text{C}$ | 26 | A | |
| I_ | 1, | 18-70 0 | 15 | A | |
| I _{Cnom} | I _{CRM} = 3 x I _{Cnom} | | 45 | A | |
| I _{CRM} V _{GES} | | | -20 20 | V | |
| V GES | V _{CC} = 800 V | | -20 20 | V | |
| t _{psc} | V _{GE} ≤ 15 V V _{CES} ≤ 1200 V | T _j = 150 °C | 10 | μs | |
| Tj | | | -40 175 | °C | |
| IGBT 7 - 1 | 12 | | | u . | |
| V _{CES} | T _i = 25 °C | | 1200 | V | |
| Ic | λ _{paste} =0.8 W/(mK) | T _s = 25 °C | 41 | Α | |
| | T _j = 175 °C | T _s = 70 °C | 34 | Α | |
| Ic | λ _{paste} =2.5 W/(mK) | T _s = 25 °C | 45 | Α | |
| | T _i = 175 °C | T _s = 70 °C | 37 | A | |
| I _{Cnom} | | - | 25 | А | |
| I _{CRM} | I _{CRM} = 3 x I _{Cnom} | | 75 | Α | |
| V _{GES} | 0 | | -20 20 | V | |
| t _{psc} | $V_{CC} = 800 \text{ V}$ $V_{GE} \le 15 \text{ V}$ $V_{CES} \le 1200 \text{ V}$ | T _j = 150 °C | 10 | μs | |
| T _i | V CES = 1200 V | 1 | -40 175 | °C | |
| Diode 1 - | 6 | | | | |
| V _{RRM} | T _i = 25 °C | | 1200 | V | |
| I _F | $\lambda_{\text{paste}} = 0.8 \text{ W/(mK)}$ | T _s = 25 °C | 23 | A | |
| ·F | $T_i = 175 ^{\circ}\text{C}$ | $T_s = 70 ^{\circ}\text{C}$ | 19 | A | |
| I _F | , | $T_s = 25 ^{\circ}\text{C}$ | 25 | A | |
| 'F | $\lambda_{\text{paste}} = 2.5 \text{ W/(mK)}$ $T_i = 175 ^{\circ}\text{C}$ | $T_s = 70 ^{\circ}\text{C}$ | 20 | A | |
| I_ | 1, 110 | 18-70 0 | 15 | A | |
| I _{Fnom} | $I_{FRM} = 3xI_{Fnom}$ | | 45 | A | |
| IFRM | | – 150 °C | 65 | A | |
| T _i | 10 ms, sin 180°, T _j = 150 °C | | -40 175 | °C | |
| | 10 | | 10 17 0 | | |
| Diode 7 - | T _i = 25 °C | I | 1200 | V | |
| V _{RRM} | | T _s = 25 °C | 1200 32 | | |
| l _F | $\lambda_{\text{paste}} = 0.8 \text{ W/(mK)}$ $T_{\text{i}} = 175 ^{\circ}\text{C}$ | $T_s = 25 ^{\circ}\text{C}$ $T_s = 70 ^{\circ}\text{C}$ | | Α | |
| I_ | | | 26 | A | |
| lF | λ_{paste} =2.5 W/(mK) T _i = 175 °C | $T_s = 25 ^{\circ}\text{C}$ $T_s = 70 ^{\circ}\text{C}$ | 35 | A | |
| I_ | 1,1-170 | 15 - 70 C | 28 25 | Α | |
| I _{Fnom} | 1 2 2 1 | | | A | |
| I _{FRM} | I _{FRM} = 3 x I _{Fnom} | | | A | |
| I _{FSM} | 10 ms, sin 180°, T _j = 150 °C | | 100 | A | |
| T _j | | | -40 175 | °C | |
| Module | 100.4 | Т | | 1 - | |
| I _{t(RMS)} | 20 A per spring | | 40 | A | |
| T _{stg} | | | -40 125 | °C | |
| V_{isol} | AC sinus 50 Hz, 1 | min | 2500 | V | |



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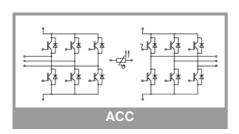
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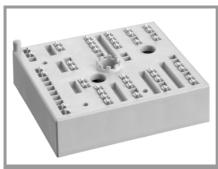
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| Characte | eristics | | | | | |
|----------------------|---|---|------|------------|-----------|----------|
| Symbol | Conditions | | min. | typ. | max. | Unit |
| IGBT 1 - 6 | , 5 | | | | | |
| V _{CE(sat)} | I _C = 15 A | T _j = 25 °C | | 1.85 | 2.10 | V |
| () | V _{GE} = 15 V | T _i = 150 °C | | 2.25 | 2.45 | V |
| V | chiplevel | T _i = 25 °C | | | | V |
| V _{CE0} | chiplevel | $T_i = 25 \text{ C}$ $T_i = 150 \text{ °C}$ | | 0.80 | 0.90 | V |
| <u> </u> | V 45.V | $T_i = 150^{\circ} \text{C}$ | | | 0.80 | |
| r _{CE} | V _{GE} = 15 V chiplevel | $T_i = 25 \text{ C}$ $T_i = 150 \text{ °C}$ | | 70 103 | 80 110 | mΩ |
| V | $V_{GE} = V_{CE} V, I_C = 1$ | , | 5 | 5.8 | 6.5 | V |
| V _{GE(th)} | _ | T _i = 25 °C | 3 | 0.1 | 0.3 | 1 |
| I _{CES} | V _{GE} = 0 V V _{CE} = 1200 V | 1, - 23 0 | | 0.1 | 0.5 | mA mA |
| C. | 10E - 1200 1 | f = 1 MHz | | 0.90 | | nF |
| Cies | V _{CE} = 25 V | f = 1 MHz | | | | nF |
| Coes | $V_{GE} = 0 V$ | f = 1 MHz | | 0.08 | | nF |
| C _{res} | V _{GE} = - 8 V+ 15 V | | | 0.06 85 | | nC |
| - | $T_i = 25 ^{\circ}\text{C}$ | <u>'</u> | | | | Ω |
| R _{Gint} | $V_{CC} = 600 \text{ V}$ | T _i = 150 °C | | 0.0 78 | | |
| t _{d(on)} | $I_{\rm C} = 15 {\rm A}$ | T _i = 150 °C | | | | ns |
| t _r | $R_{G \text{ on}} = 39 \Omega$ | T _i = 150 °C | | 64 | | ns |
| E _{on} | $R_{G \text{ off}} = 39 \Omega$ | 1 1 | | 1.89 | | mJ |
| t _{d(off)} | $di/dt_{on} = 200 \text{ A/}\mu\text{s}$ $di/dt_{off} = 189 \text{ A/}\mu\text{s}$ | T _j = 150 °C | | 340 | | ns |
| t _f | du/dt = 3600 V/µs | T _j = 150 °C | | 67 | | ns |
| E_{off} | $V_{GE} = +15/-15 \text{ V}$ $L_s = 22 \text{ nH}$ | T _j = 150 °C | | 1.64 | | mJ |
| R _{th(j-s)} | per IGBT, λ _{paste} =0. | 8 W/(mK) | | 1.3 | | K/W |
| R _{th(j-s)} | per IGBT, λ _{paste} =2. | 5 W/(mK) | | 1.1 | | K/W |
| IGBT 7 - 1 | 12 | | | | | • |
| V _{CE(sat)} | $I_{\rm C} = 25 {\rm A}$ | T _j = 25 °C | | 1.85 | 2.10 | V |
| | V _{GE} = 15 V | T _j = 150 °C | | 2.25 | 2.45 | V |
| V _{CE0} | chiplevel | T _i = 25 °C | | 0.80 | 0.90 | V |
| V CE0 | - chiplevel | T _i = 150 °C | | 0.70 | 0.80 | V |
| ron | V15 V | T _i = 25 °C | | 42 | 48 | mΩ |
| r _{CE} | V _{GE} = 15 V chiplevel | T _i = 150 °C | | 62 | 66 | mΩ |
| V _{GE(th)} | $V_{GE} = V_{CE} V, I_C = 1$ | 1 * | 5 | 5.8 | 6.5 | V |
| I _{CES} | $V_{GE} = 0 \text{ V}$ | T _i = 25 °C | | 0.1 | 0.3 | mA |
| ICES | $V_{CE} = 1200 \text{ V}$ | 1,1-20 0 | | - | 0.0 | mA |
| C _{ies} | 1 02 | f = 1 MHz | | 1.43 | | nF |
| Coes | V _{CE} = 25 V | f = 1 MHz | | 0.12 | | nF |
| C _{res} | $V_{GE} = 0 V$ | f = 1 MHz | | 0.09 | | nF |
| Q _G | V _{GE} = - 8 V+ 15 V | | | 142 | | nC |
| R _{Gint} | $T_j = 25 ^{\circ}\text{C}$ | | | 0 | | Ω |
| t _{d(on)} | $V_{CC} = 600 \text{ V}$ | T _i = 150 °C | | 87 | | ns |
| t _r | I _C = 25 A | T _i = 150 °C | | 61 | | ns |
| E _{on} | $R_{G \text{ on}} = 39 \Omega$ | T _i = 150 °C | | 3.5 | | mJ |
| | $R_{G \text{ off}} = 39 \Omega$ | T _i = 150 °C | | 400 | | |
| t _{d(off)} | di/dt _{on} = 325 A/μs di/dt _{off} = 330 A/μs | $T_i = 150 \text{ C}$ $T_i = 150 \text{ °C}$ | | 61 | | ns |
| t _f | du/dt _{off} = 350 A/μs du/dt = 3500 V/μs | 1 _j = 150 C | | ΟI | | ns |
| E_{off} | $V_{GE} = +15/-15 \text{ V}$ $L_s = 22 \text{ nH}$ | T _j = 150 °C | | 2.7 | | mJ |
| R _{th(j-s)} | | per IGBT, λ _{paste} =0.8 W/(mK) | | 1 | | K/W |
| R _{th(j-s)} | per IGBT, λ _{paste} =2. | E M//m// | | 0.84 | | K/W |



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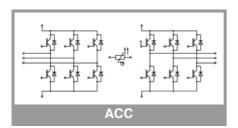
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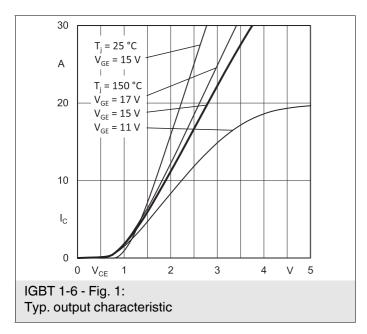
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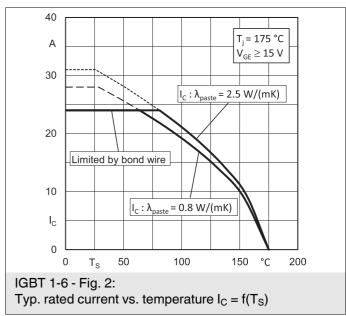
Remarks

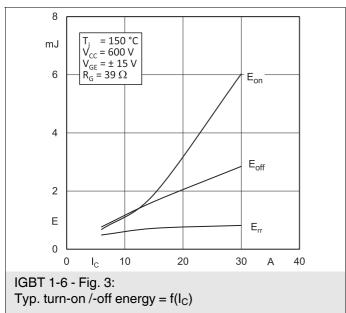
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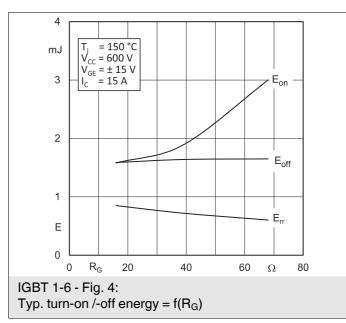
| Characte | Characteristics | | | | | | | | |
|----------------------|---|-------------------------|----------|-----------|------|-----------|--|--|--|
| Symbol | Conditions | | min. | typ. | max. | Unit | | | |
| Diode 1 - 6 | | | | | | | | | |
| * F - * EC | I _F = 15 A | T _j = 25 °C | | 2.38 | 2.71 | V | | | |
| | V _{GE} = 0 V chiplevel | T _j = 150 °C | | 2.44 | 2.77 | V | | | |
| V _{F0} | chiplevel | T _j = 25 °C | | 1.30 | 1.50 | V | | | |
| | | T _j = 150 °C | | 0.90 | 1.10 | V | | | |
| r _F | chiplevel | T _j = 25 °C | | 72 | 81 | $m\Omega$ | | | |
| | or inprover | T _j = 150 °C | | 103 | 111 | mΩ | | | |
| I _{RRM} | I _F = 15 A | T _j = 150 °C | | 10.7 | | Α | | | |
| Q _{rr} | di/dt _{off} = 260 A/μs V _{GE} = -15 V | T _j = 150 °C | | 2.2 | | μC | | | |
| E _{rr} | $V_{CC} = 600 \text{ V}$ | T _j = 150 °C | | 0.72 | | mJ | | | |
| R _{th(j-s)} | per Diode, λ _{paste} =0 | .8 W/(mK) | | 1.92 | | K/W | | | |
| R _{th(j-s)} | per Diode, λ _{paste} =2.5 W/(mK) | | | 1.7 | | K/W | | | |
| Diode 7 - | 12 | | | | | | | | |
| $V_F = V_{EC}$ | I _F = 25 A | T _j = 25 °C | | 2.41 | 2.74 | V | | | |
| | V _{GE} = 0 V chiplevel | T _j = 150 °C | | 2.45 | 2.79 | V | | | |
| V_{F0} | chiplevel | T _j = 25 °C | | 1.30 | 1.50 | V | | | |
| | Chipievei | T _j = 150 °C | | 0.90 | 1.10 | V | | | |
| r _F | chiplevel | T _j = 25 °C | | 44 | 50 | mΩ | | | |
| | | T _j = 150 °C | | 62 | 68 | mΩ | | | |
| I _{RRM} | I _F = 25 A | T _j = 150 °C | | 13.8 | | Α | | | |
| Q _{rr} | $di/dt_{off} = 320 \text{ A/}\mu\text{s}$ $V_{GF} = -15 \text{ V}$ | T _j = 150 °C | | 3.3 | | μC | | | |
| E _{rr} | $V_{CC} = 600 \text{ V}$ | T _j = 150 °C | | 1.15 | | mJ | | | |
| R _{th(j-s)} | per Diode, λ _{paste} =0.8 W/(mK) | | | 1.52 | | K/W | | | |
| R _{th(j-s)} | per Diode, λ _{paste} =2.5 W/(mK) | | | 1.3 | | K/W | | | |
| Module | | | | | | | | | |
| L _{CE} | | | | 30 | | nΗ | | | |
| Ms | to heat sink | | 2 | | 2.5 | Nm | | | |
| w | | | | 55 | | g | | | |
| Temperat | ure Sensor | | <u>-</u> | | | | | | |
| R ₁₀₀ | T _r =100°C (R ₂₅ =1000Ω) | | | 1670 ± 3% | | Ω | | | |
| R(T) | R(T)=1000Ω[1+A(T)], A = 7.635*10 ⁻³ °C B = 1.731*10 ⁻⁵ °C ⁻² | | | | | | | | |

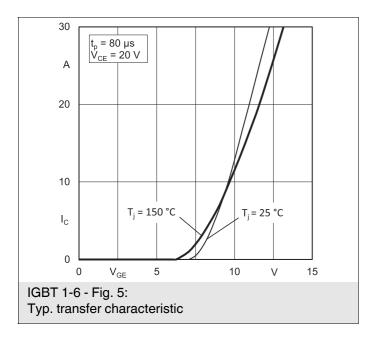


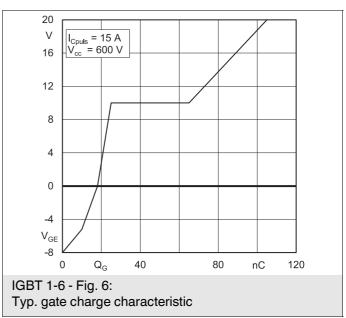


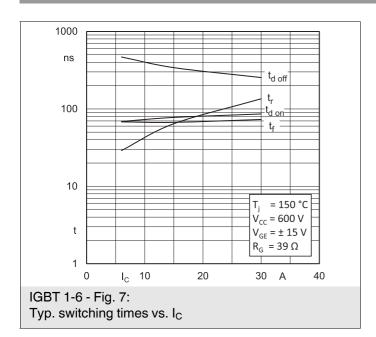


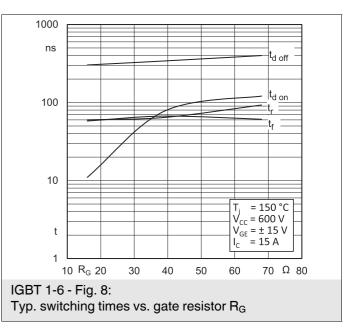


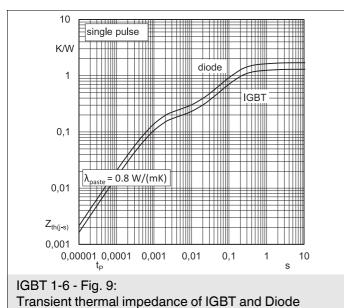


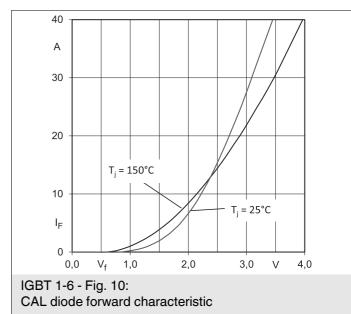


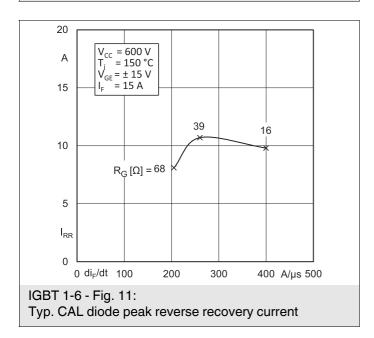


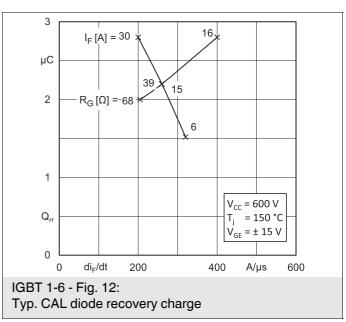


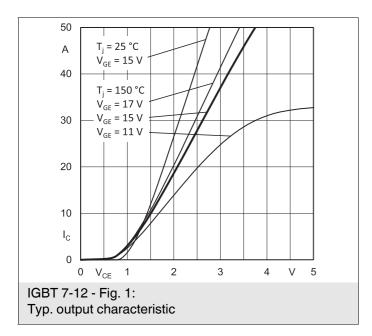


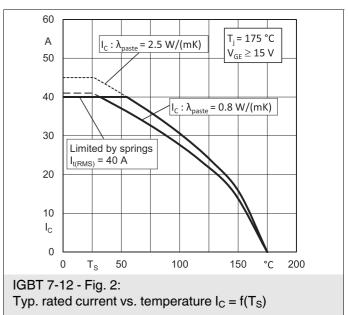


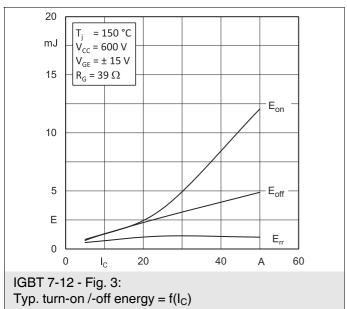


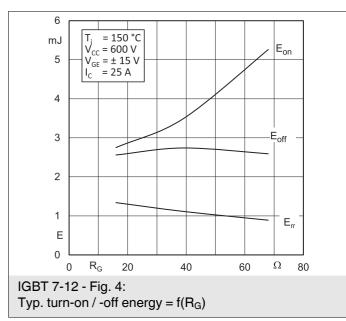


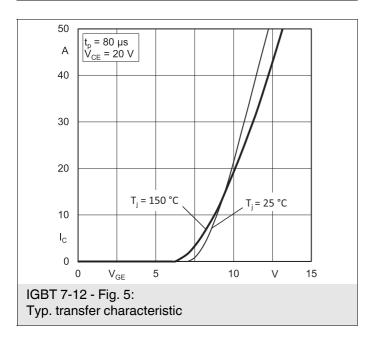


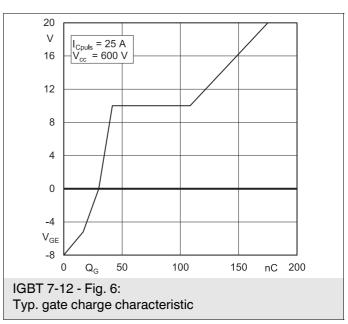


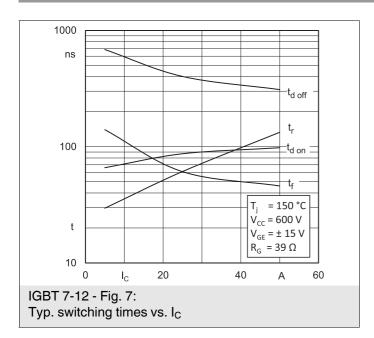


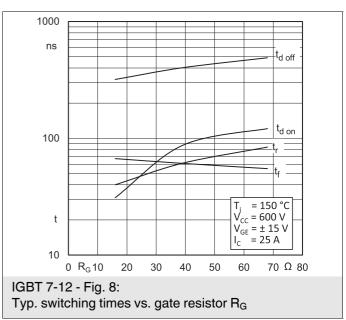


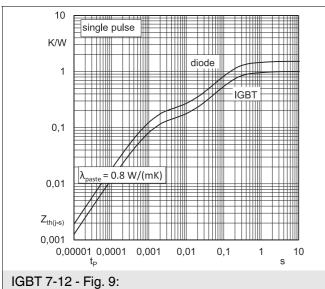




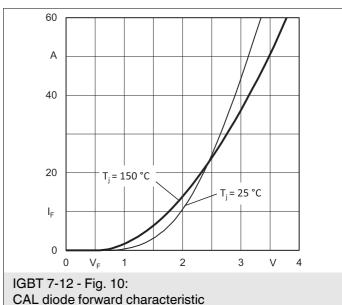


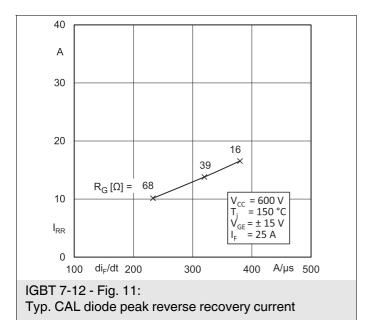


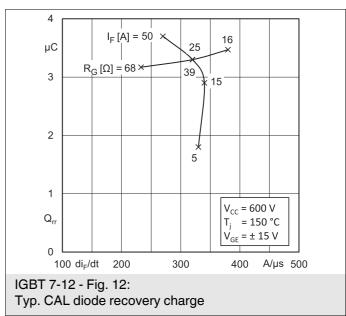


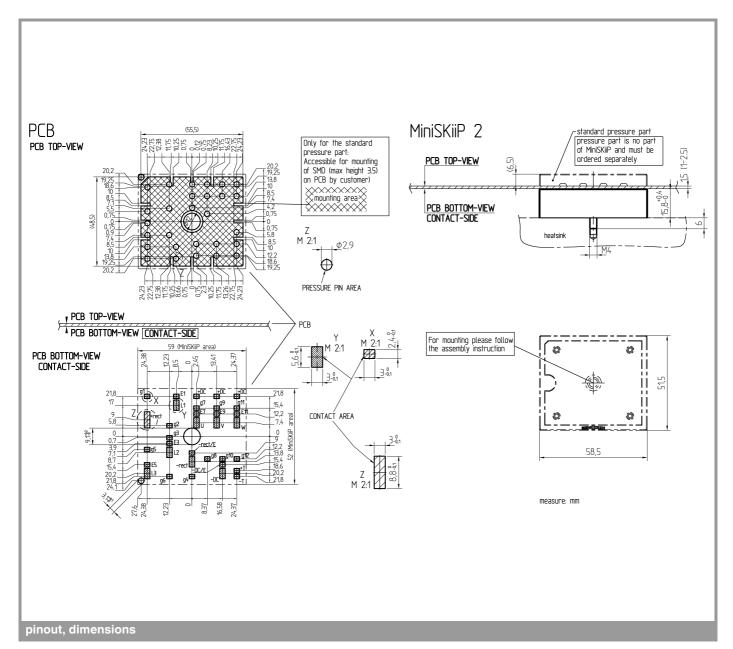


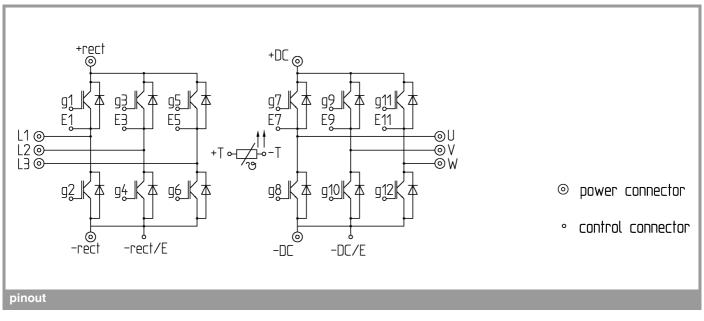












This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, chapter IX.

*IMPORTANT INFORMATION AND WARNINGS

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